



## NCE6005AS

#### NCE N-Channel Enhancement Mode Power MOSFET

#### **Description**

The NCE6005AS uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

V<sub>DS</sub>=60V,I<sub>D</sub>=5A

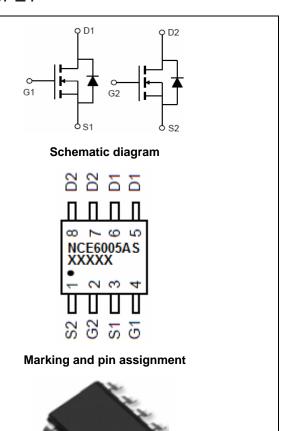
 $R_{DS(ON)}$  <35m $\Omega$  @  $V_{GS}$ =10V (Typ.26m $\Omega$ )

 $R_{DS(ON)}$  <45m $\Omega$  @  $V_{GS}$ =4.5V (Typ.32m $\Omega$ )

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation

#### **Application**

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply



SOP-8 top view

#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE6005AS	NCE6005AS	SOP-8	Ø330mm	12mm	2500 units

#### Absolute Maximum Ratings (T<sub>A</sub>=25℃unless otherwise noted)

	<u>'</u>		
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	60	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	5	Α
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100℃)	3.5	А
Pulsed Drain Current	I <sub>DM</sub>	24	А
Maximum Power Dissipation	P <sub>D</sub>	2	W
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	℃

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	62.5	°C/W



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## NCE6005AS

## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	60	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	-	-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.2	1.6	2.5	V
Desir Course On State Besistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =5A	-	26	35	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =5A	-	32	45	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =5A	11	-	-	S
Dynamic Characteristics (Note4)			•			•
Input Capacitance	C <sub>lss</sub>	\/ 20\/\/ 0\/	-	979	-	PF
Output Capacitance	Coss		-	120	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.UMHZ	-	100	-	PF
Switching Characteristics (Note 4)		,	•	ı		
Turn-on Delay Time	t <sub>d(on)</sub>		-	5.2	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DS}=5V, I_{D}=5A$ $V_{DS}=5V, I_{D}=5A$ $V_{DS}=30V, V_{GS}=0V, F=1.0MHz$ $V_{DD}=30V, R_{L}=6.7\Omega$	-	3	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =3 $\Omega$	-	17	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	2.5	-	nS
Total Gate Charge	Qg	\/ 20\/ L 5A	-	22		nC
Gate-Source Charge	$Q_{gs}$	$V_{DS}=30V,I_{D}=5A,$	-	3.3		nC
Gate-Drain Charge	$Q_{gd}$	- V <sub>GS</sub> =10V	-	5.2		nC
Drain-Source Diode Characteristics			•			•
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =5A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	5	Α
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is neg	ligible (turi	n-on is do	ominated b	y LS+LD)
		•				

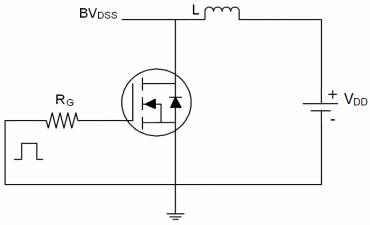
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition:Tj=25  $^{\circ}\text{C}$  ,VDD=30V,VG=10V,L=0.5mH,Rg=25 $\Omega$

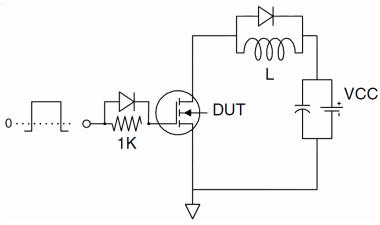
# NCE6005AS

#### **Test Circuit**

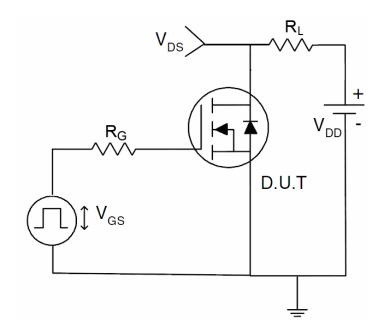
### 1) E<sub>AS</sub> test Circuit



#### 2) Gate charge test Circuit

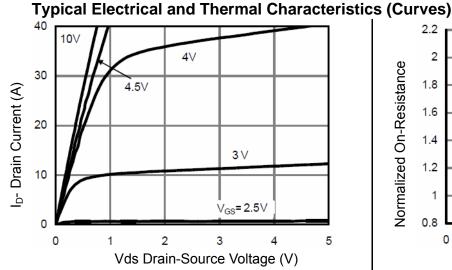


### 3) Switch Time Test Circuit

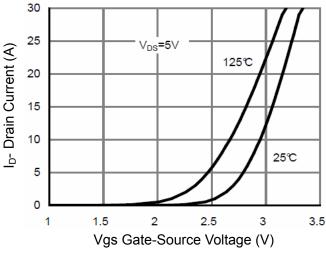


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**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

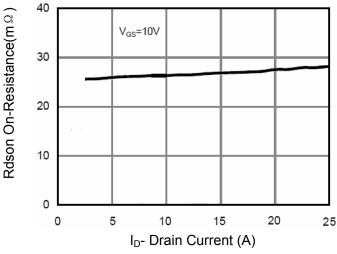
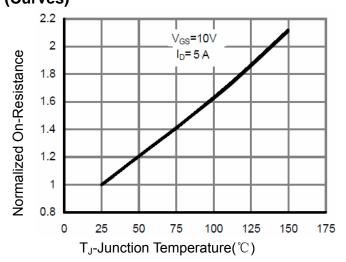


Figure 3 Rdson- Drain Current



**Figure 4 Rdson-Junction Temperature** 

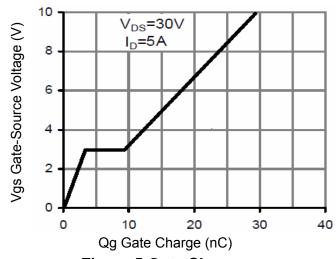


Figure 5 Gate Charge

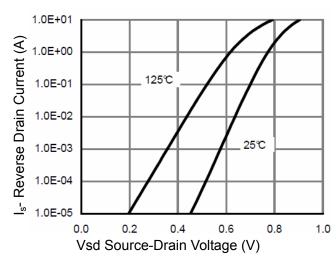
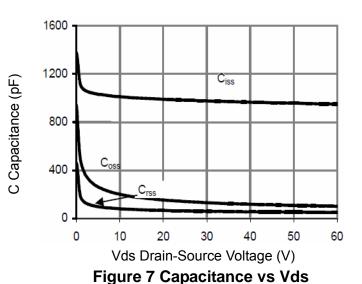


Figure 6 Source- Drain Diode Forward

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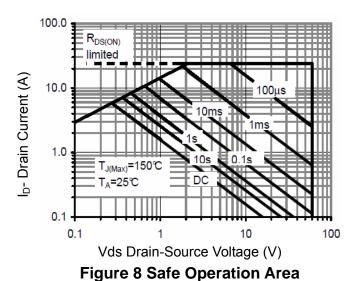


Figure 9 BV<sub>DSS</sub> vs Junction Temperature

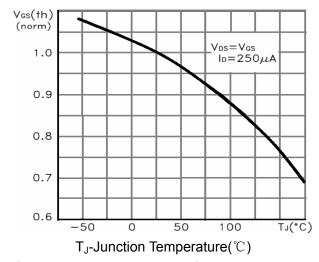
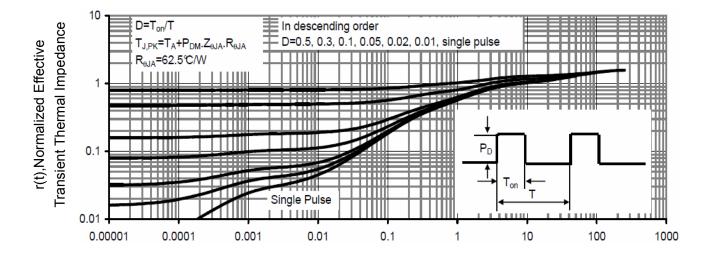


Figure 10 V<sub>GS(th)</sub> vs Junction Temperature



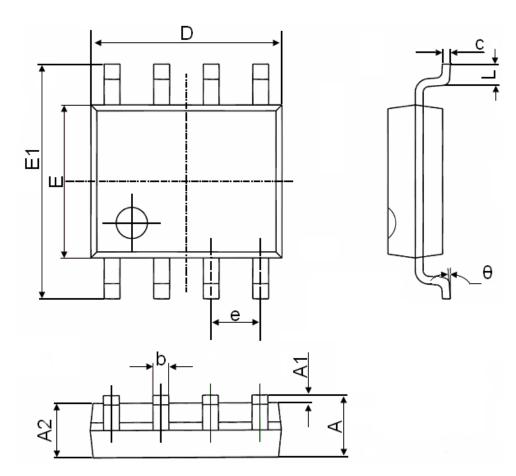
Square Wave Pluse Duration (sec)

Figure 11 Normalized Maximum Transient Thermal Impedance

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## **SOP-8 Package Information**



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
Α	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
Е	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.270(BSC)		0.050(B	BSC)	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	



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